

AM Receiver Circuit

Technology: Bipolar

Features

- Controlled RF preamplifier
- Multiplicative balanced mixer
- Separate oscillator with amplitude control
- IF amplifier with gain control
- Balanced full-wave detector
- Audio preamplifier
- Internal AGC voltage
- Amplifier for field-strength indication
- Electronic stand-by on/off switch

Case: 16 pin dual inline plastic

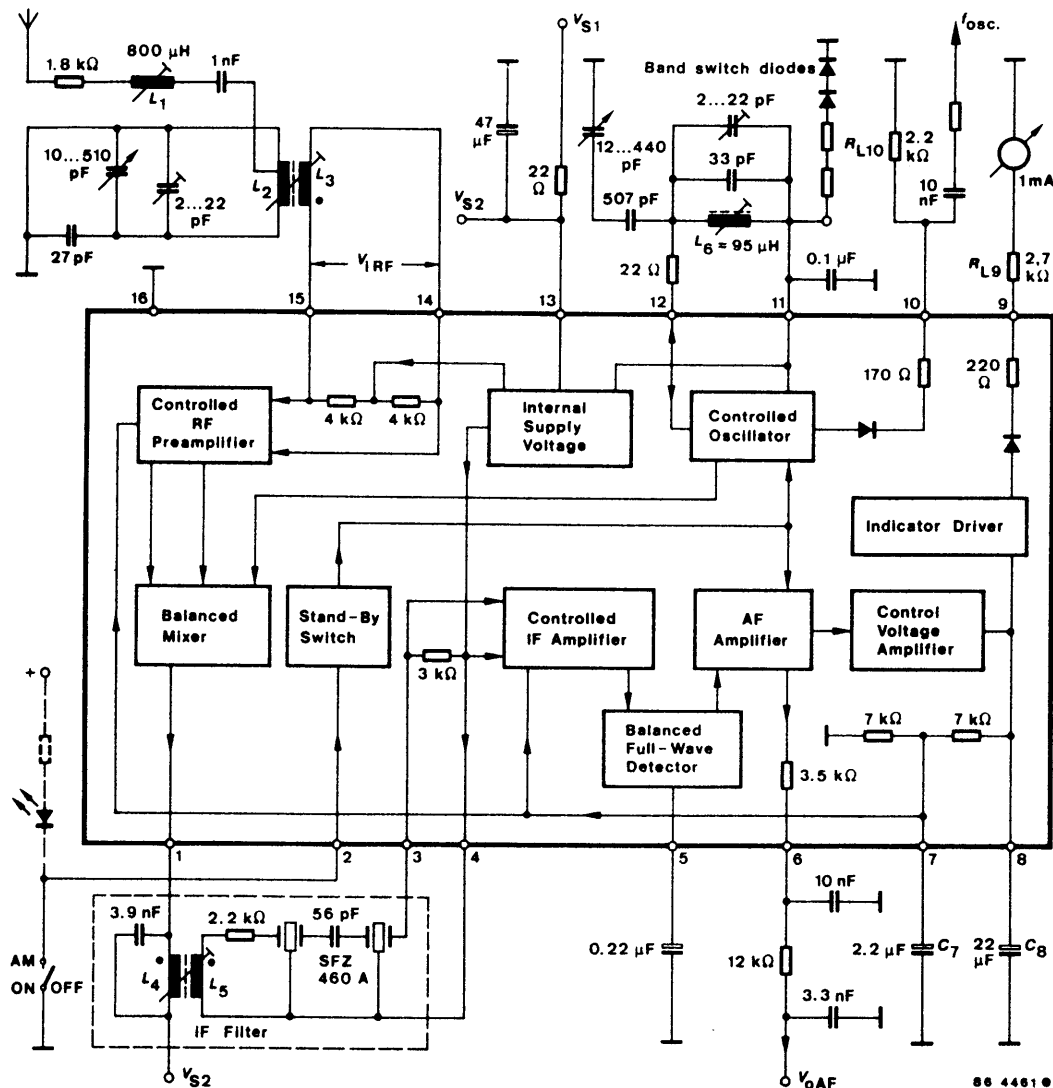


Figure 1 Block diagram and application circuit

Absolute maximum ratings

Reference point pin 16, unless otherwise specified

Parameters	Symbol	Value	Unit
Supply voltage Pin 13	V_S	20	V
Voltage on Pin 2	V_2	0 to 20	V
RF inputs Voltages Reference point 15			
Pin 14	$\pm V_{i\ 14/15}$	12	V
Pin 14	V_i	V_S	V
Pin 14	$-V_i$	0.6	V
Pin 15	V_i	V_i	V
Pin 15	$-V_i$	0.6	V
RF inputs Currents Pin 14, 15	$\pm I_i$	200	mA
Ambient temperature range	T_{amb}	- 30 to + 80	°C
Storage temperature range	T_{stg}	- 55 to + 150	°C

Electrical Characteristics

$V_S = 8.5$ V, reference point pin 16, $f_{IRF} = 1$ MHz, $R_G = 50\ \Omega$, $f_{mod} = 0.4$ kHz, $m = 30\%$, $f_{IF} = 460$ kHz, $T_{amb} = + 25$ °C, unless otherwise specified

Parameters	Test Conditions / Pin	Symbol	Min	Type	Max	Unit
Supply voltage range	Pin 13	V_S	7.5	18		V
Supply current, without load, $I_L = 0$ (Pin 11)	Pin 13	I_S		23	30	mA
RF preamplifier and mixer						
DC input voltages	Pin 14, 15	V_i		$V_S/2$		V
Input impedances	$V_{iRF} < 300\ \mu V$, Pin 14, 15	R_i		5.5		k Ω
		C_i		25		pF
	$V_{iRF} > 10$ mV, Pin 14, 15	R_i		8.0		k Ω
		C_i		22		pF
Output impedance	Pin 1	R_o	500			k Ω
		C_o		6.0		pF
Maximum conversion conductance	$I_o\ 1\ IF/V_{iRF}$	ΔS_M			6.5	mA/V
Maximum IF output voltage	Pin 1	V_{oIF}			5.0	V _{pp}
Output current	Pin 1	I_o		1.2		mA
Preamplifier control range		S_M		30		dB
Max. RF input voltage	Pin 14, 15	V_i			2.5	V _{pp}
Oscillator						
Frequency range	Pin 12	f_{OSC}	0.6		60	MHz
Oscillator circuit impedance range	Pin 12	Z_{LOSC}	0.5		200	k Ω

Parameters	Test Conditions / Pin	Symbol	Min	Type	Max	Unit
Controlled oscillator amplitude	Pin 12	V_{OSC}		130	150	mV
DC output voltage	$I_L = 0$ V Pin 11	V_O		$6 V_{BE(4V)}$		V
Output load current range	Pin 11	$-I_L$			20	mA
Output resistance	$I_L = 5 \pm 0.5$ mA, Pin 11	R_O		25		Ω
Oscillator frequency output Pin 10						
Output voltage	$R_{L10} = 4.7$ k Ω	V_0		320		mV _{pp}
Output resistance		R_0		170		Ω
Allowable output current		I_0			3	mA _p
IF amplifier an AF stage						
DC input voltages	Pin 3, 4	V_i		2		V
Input impedance	Pin 3	R_i C_i	2.4	3 7	3.9	k Ω pF
Max. IF input voltage	m = 80%, d = 3% Pin 3	V_i		90		mV
Control range	$V_{0AF} = -6$ dB	ΔV_i	61			dB
Audio output voltage	Pin 6 $V_i = 1$ mV (Pin 3), without load	V_0		310		mV
Audio output resistance	Pin 6	R_0		3.5		k Ω
Field-strength indication						
DC indicator voltages	$R_{L9} = 2.7$ k Ω , $V_i = 0$ Pin 9 $V_i = 500$ mV Pin 9	V_O V_O	0 2.5		140 3.1	mV V
Output current capability	Pin 9	$-I_O$	2.0			mA
Output resistance	$-I_0 = 0.5$ mA Pin 9	R_0		220		Ω
Reverse voltage at the output	AM switch-Off, $\pm I_0 \leq 1$ μ A	V_0		6		V
Stand-by switch						
Switching voltage	Pin 2	V_i		2.75		V
Required control voltage	AM ON Pin 2 AM OFF Pin 2	V_i $V_i^{1)}$	3.5		2	V V
Input current	AM on, switching current AM off, reverse current ($V_2 = V_3$), Pin 2	$-I_i$ $\pm I_i$			200 10	μ A μ A

¹⁾ or open input

Operating conditions

$V_S = 8.5 \text{ V}$, $f_{iRF} = 1 \text{ MHz}$, $f_{mod} = 0.4 \text{ kHz}$, $m = 30\%$, $T_{amb} = 25^\circ\text{C}$, reference point Pin 16, see figure 2, unless otherwise specified

Parameters	Test Conditions / Pin	Symbol	Min	Type	Max	Unit
RF input voltages	$(S + N)/N$ = 6 dB = 26 dB = 46 dB	V_{iRF} V_{iRF} V_{iRF}		1.5 15 150		μV μV μV
RF input for agc operation		V_{iRF}		30		μV
Control range for	(Reference value $V_i = 500 \text{ mV}$) $\Delta V_0 = 6 \text{ dB}$ $\Delta V_0 = 1 \text{ dB}$	ΔV_{iRF} ΔV_{iRF}		91 86		dB dB
Maximum RF input voltage	$d = 3\%$, $m = 80\%$ $d = 3\%$, $m = 30\%$ $d = 10\%$, $m = 30\%$	V_{iRF} V_{iRF} V_{iRF}		0.5 0.7 0.9		V V V
Audio output voltage	$V_1 = 1 \text{ mV}$ $V_2 = 4 \mu\text{V}$, $m = 0.8$	V_{0AF} V_{0AF}		310 ($\pm 2 \text{ dB}$) 130 ($\pm 3.5 \text{ dB}$)		mV mV
RF input voltage	$V_{0AF} = 60 \text{ mV}$	V_{iRF}		5.5		μV
Total distortion of audio output voltage	$m = 80\%$, $V_i = 1 \text{ mV}$ $V_i = 500 \text{ mV}$	d d		0.5 3.0		% %
Signal plus noise to noise ratio of audio output voltage	$V_i = 1 \text{ mV}$	$\frac{(S + N)}{N}$		50		dB
IF bandwidth (-3 dB)		B_{iF}		4.6		kHz
IF selectively	$\Delta f = \pm 9 \text{ kHz}$ $\Delta f = \pm 36 \text{ kHz}$	S_{iF} S_{iF}		30 60		dB dB

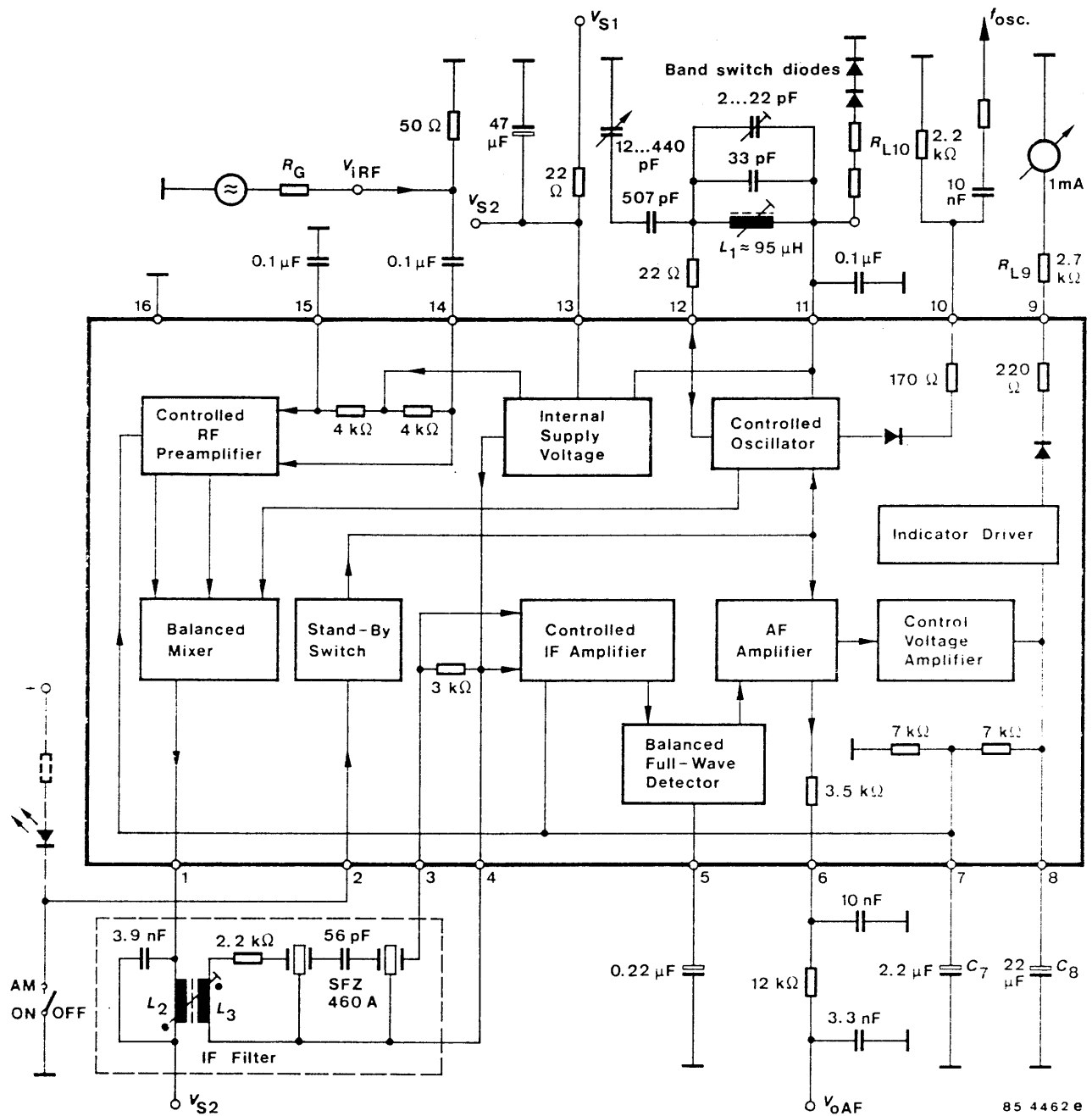
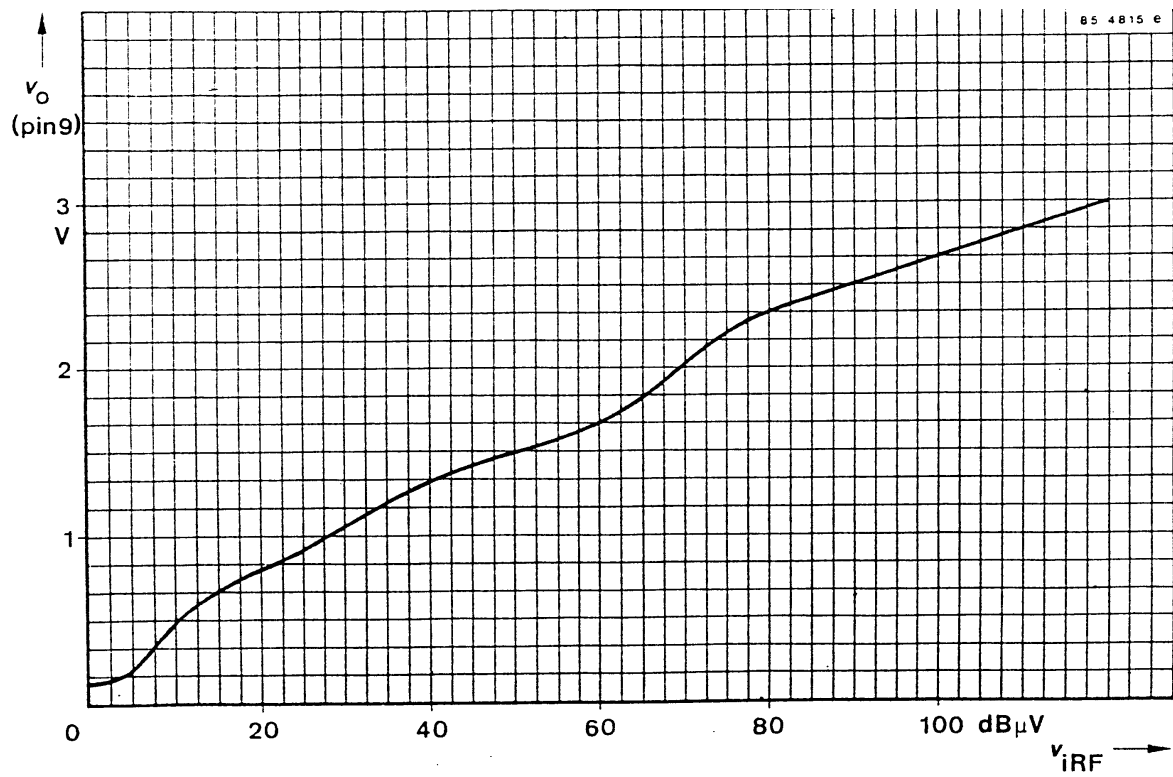
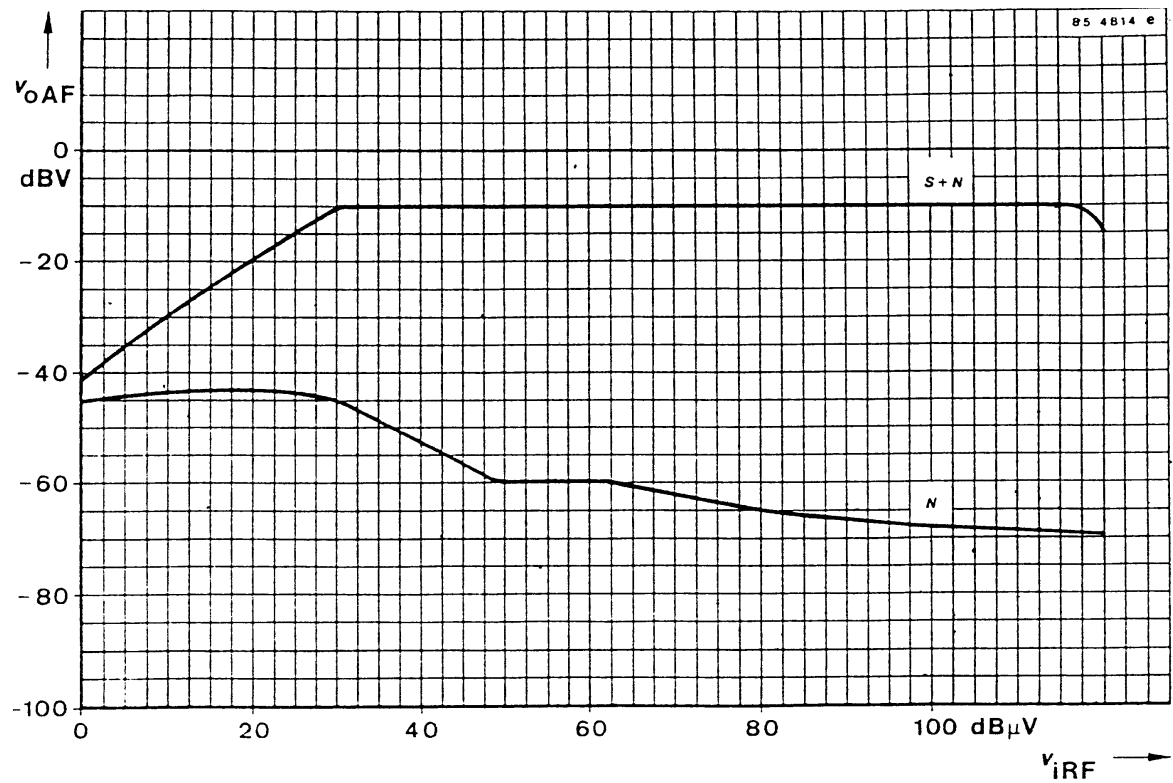
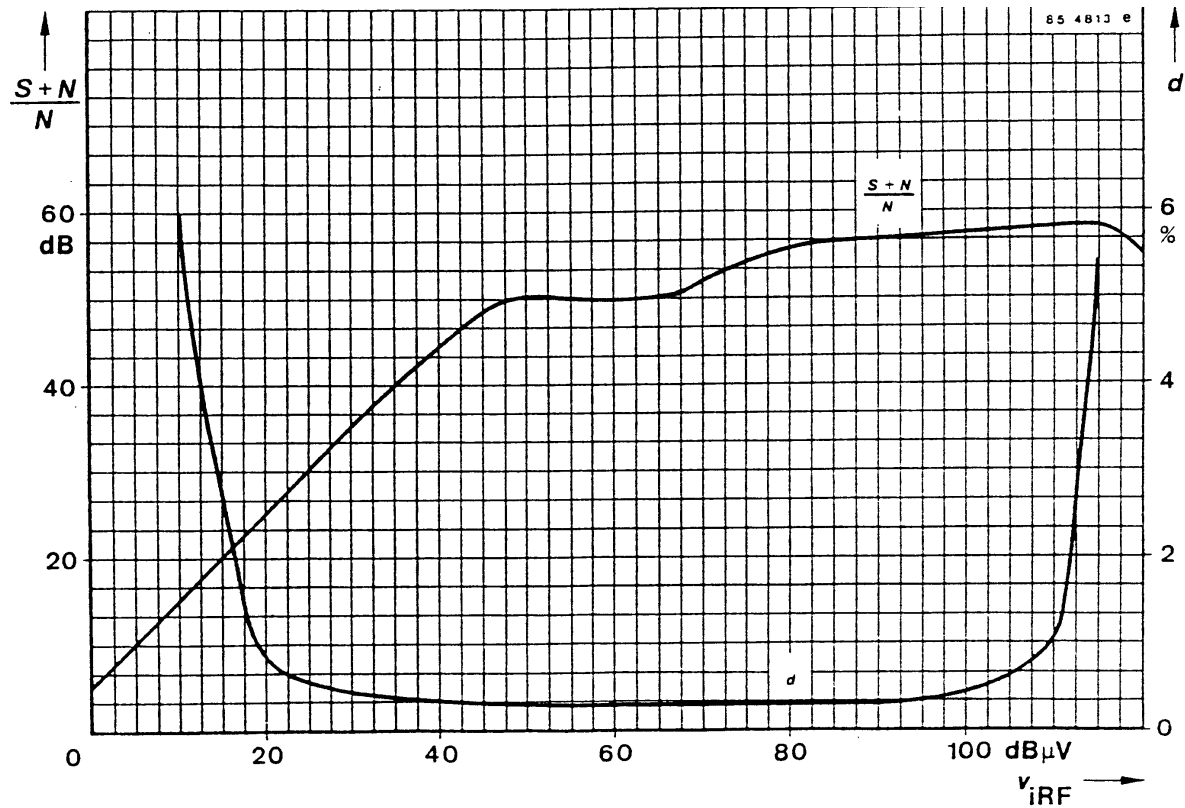
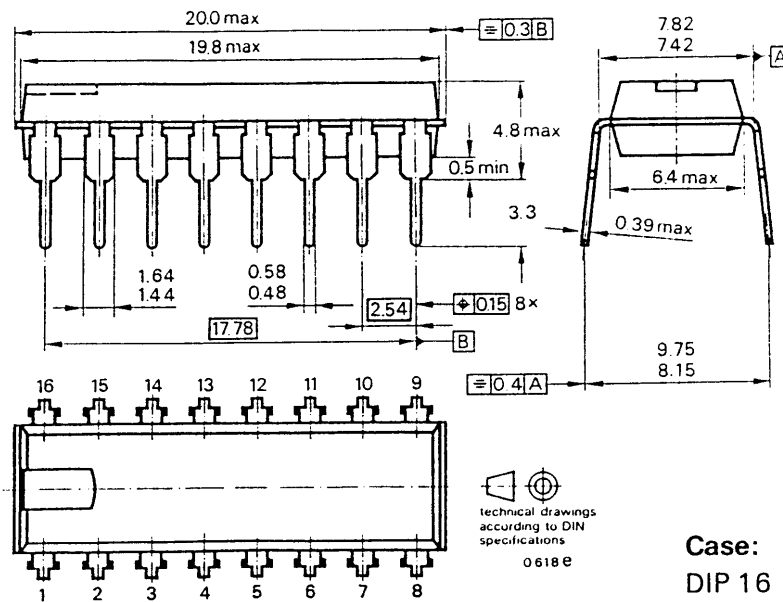


Figure 2 Test circuit





Dimensions in mm



Case:
DIP 16

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1. Meet all present and future national and international statutory requirements and
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

Of particular concern is the control or elimination of releases into the atmosphere of those substances which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) will soon severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

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1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
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3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

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TEMIC TELEFUNKEN microelectronic GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0)7131 67 2831, Fax Number: 49 (0)7131 67 2423